

TC74VHCT574AF, TC74VHCT574AFW, TC74VHCT574AFT

OCTAL D - TYPE FLIP - FLOP WITH 3 - STATE OUTPUT

The TC74VHCT574A is an advanced high speed CMOS OCTAL FLIP - FLOP with 3 - STATE OUTPUT fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8 - bit D - type flip - flop is controlled by a clock input (CK) and a output enable input (OE). When the OE input is high, the eight outputs are in a high impedance state. The input voltage are compatible with TTL output voltage. This device may be used as a level converter for interfacing 3.3V to 5V system. Input protection and output circuit ensure that 0 to 5.5V can be applied to the input and output*1 pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input / output voltages such as battery back up, hot board insertion, etc.

*1: output in off-state

FEATURES :

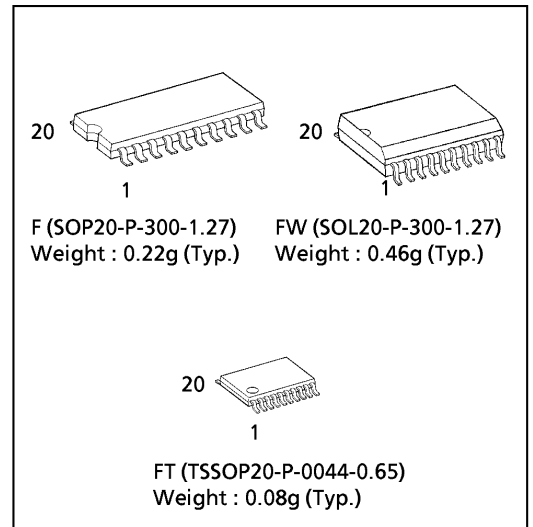
- High Speed..... $f_{MAX} = 140\text{MHz}(\text{typ.})$
at $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$ at $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs.... $V_{IL} = 0.8\text{V}(\text{Max.})$
 $V_{IH} = 2.0\text{V}(\text{Min.})$
- Power Down Protection is provided on all inputs and outputs.
- Balanced Propagation Delays..... $t_{PLH} \approx t_{PHL}$
- Low Noise $V_{OLP} = 1.6\text{V}(\text{Max.})$
- Pin and Function Compatible with the 74 series (74AC / HC / F / ALS / LS etc.) 574 type.

TRUTH TABLE

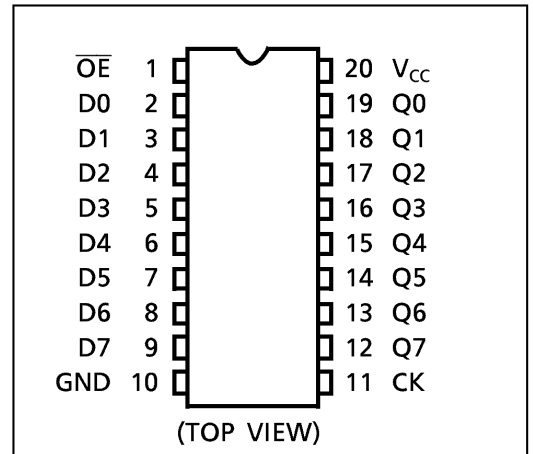
| INPUTS | | | OUTPUT |
|--------|----|---|----------------|
| OE | CK | D | |
| H | X | X | Z |
| L | | X | Q _n |
| L | | L | L |
| L | | H | H |

X : Don't Care
Z : High Impedance
Q_n : No Change

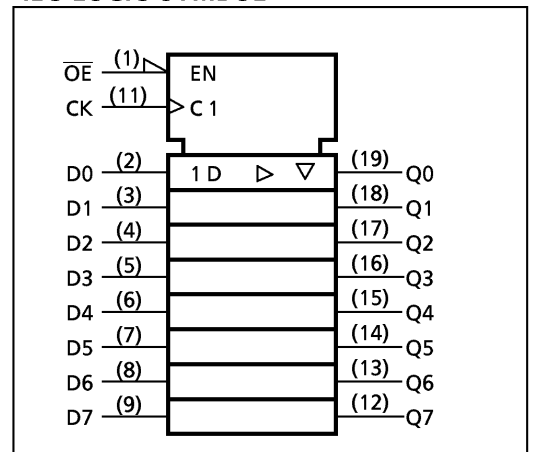
(Note) The JEDEC SOP (FW) is not available in Japan.



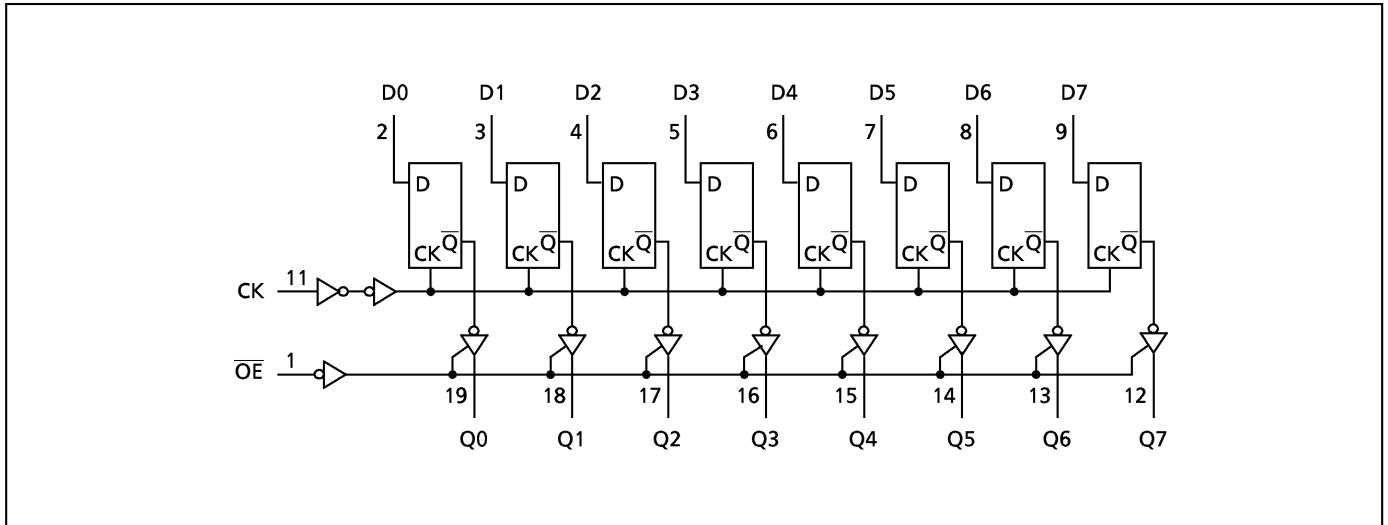
PIN ASSIGNMENT



IEC LOGIC SYMBOL



SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | VALUE | UNIT |
|-----------------------|-----------|-------------------------------|------|
| Supply Voltage Range | V_{CC} | -0.5~7.0 | V |
| DC Input Voltage | V_{IN} | -0.5~7.0 | V |
| DC Output Voltage | V_{OUT} | -0.5~7.0 (Note 1) | V |
| | | -0.5~ $V_{CC} + 0.5$ (Note 2) | |
| Input Diode Current | I_{IK} | -20 | mA |
| Output Diode Current | I_{OK} | ±20 (Note 3) | mA |
| DC Output Current | I_{OUT} | ±25 | mA |
| DC Vcc/Ground Current | I_{CC} | ±75 | mA |
| Power Dissipation | P_D | 180 | mW |
| Storage Temperature | T_{stg} | -65~150 | °C |

(Note 1) Output in Off-State

(Note 2) High or Low State. I_{OUT} absolute maximum rating must be observed.

(Note 3) $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | VALUE | UNIT |
|--------------------------|-----------|----------------------|------|
| Supply Voltage | V_{CC} | 4.5~5.5 | V |
| Input Voltage | V_{IN} | 0~5.5 | V |
| Output Voltage | V_{OUT} | 0~5.5 (Note 4) | V |
| | | 0~ V_{CC} (Note 5) | |
| Operating Temperature | T_{opr} | -40~85 | °C |
| Input Rise and Fall Time | dt/dV | 0~20 | ns/V |

(Note 4) Output in Off-State

(Note 5) High or Low State

DC ELECTRICAL CHARACTERISTICS

| PARAMETER | SYMBOL | CONDITON | | V _{CC} (V) | Ta = 25°C | | | Ta = -40~85°C | | UNIT |
|--------------------------------------|------------------|---|-------------------------|---------------------|-----------|------|-------|---------------|-------|------|
| | | | | | MIN. | TYP. | MAX. | MIN. | MAX. | |
| High - Level Input Voltage | V _{IH} | | | 4.5~5.5 | 2.0 | — | — | 2.0 | — | V |
| Low - Level Input Voltage | V _{IL} | | | 4.5~5.5 | — | — | 0.8 | — | 0.8 | V |
| High - Level Output Voltage | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -50μA | 4.5 | 4.40 | 4.50 | — | 4.40 | — | V |
| | | | I _{OH} = -8mA | 4.5 | 3.94 | — | — | 3.80 | — | |
| Low - Level Output Voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 50μA | 4.5 | — | 0.0 | 0.10 | — | 0.10 | V |
| | | | I _{OL} = 8mA | 4.5 | — | — | 0.36 | — | 0.44 | |
| 3 - State Output Off - State Current | I _{OZ} | V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND | | 5.5 | — | — | ±0.25 | — | ±2.50 | μA |
| Input Leakage Current | I _{IN} | V _{IN} = 5.5V or GND | | 0~5.5 | — | — | ±0.1 | — | ±1.0 | |
| Quiescent Supply Current | I _{CC} | V _{IN} = V _{CC} or GND | | 5.5 | — | — | 4.0 | — | 40.0 | |
| | I _{CCT} | PER INPUT : V _{IN} = 3.4V OTHER INPUT : V _{CC} or GND | | 5.5 | — | — | 1.35 | — | 1.50 | mA |
| Output Leakage Current | I _{OPD} | V _{OUT} = 5.5V | | 0 | — | — | +0.5 | — | +5.0 | μA |

TIMING REQUIREMENTS (Input t_r = t_f = 3ns)

| PARAMETER | SYMBOL | TEST CONDITION | V _{CC} (V) | Ta = 25°C | | Ta = -40~85°C | UNIT |
|----------------------------|--|----------------|---------------------|-----------|-------|---------------|------|
| | | | | TYP . | LIMIT | LIMIT | |
| Minimum Pulse Width (CK) | t _{W(H)} t _{W(L)} | | 5.0 ± 0.5 | — | 6.5 | 8.5 | ns |
| Minimum Set - up Time | t _s | | 5.0 ± 0.5 | — | 2.5 | 2.5 | |
| Minimum Hold Time | t _h | | 5.0 ± 0.5 | — | 2.5 | 2.5 | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

| PARAMETER | SYMBOL | TEST CONDITION | Ta = 25°C | | | Ta = -40~85°C | | UNIT | | |
|-------------------------------|--|----------------|---------------------|---------|------|---------------|------|------|------|------|
| | | | V _{CC} (V) | CL (pF) | MIN. | TYP. | MAX. | | MIN. | MAX. |
| Propagation Delay Time (CK-Q) | t _{pLH} t _{pHL} | | 5.0 ± 0.5 | 15 | — | 4.1 | 9.4 | 1.0 | 10.5 | ns |
| | | | | 50 | — | 5.6 | 10.4 | 1.0 | 11.5 | |
| 3-State Output Enable Time | t _{pZL} t _{pZH} | RL = 1kΩ | 5.0 ± 0.5 | 15 | — | 6.5 | 10.2 | 1.0 | 11.5 | |
| | | | | 50 | — | 7.3 | 11.2 | 1.0 | 12.5 | |
| 3-State Output Disable Time | t _{pLZ} t _{pHZ} | RL = 1kΩ | 5.0 ± 0.5 | 50 | — | 7.0 | 11.2 | 1.0 | 12.0 | |
| | | | | | | | | | | |
| Maximum Clock Frequency | f _{MAX} | | 5.0 ± 0.5 | 15 | 90 | 140 | — | 80 | — | MHz |
| | | | | 50 | 85 | 130 | — | 75 | — | |
| Output to Output Skew | t _{osLH} t _{osHL} | (Note 6) | 5.0 ± 0.5 | 50 | — | — | 1.0 | — | 1.0 | ns |
| Input Capacitance | C _{IN} | | | | — | 4 | 10 | — | 10 | pF |
| Output Capacitance | C _{OUT} | | | | — | 9 | — | — | — | |
| Power Dissipation Capacitance | C _{PD} | (Note 7) | | | — | 25 | — | — | — | |

(Note 6) Parameter guaranteed by design. $t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$

(Note 7) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per F/F)}$$

And the total C_{PD} when n pcs. of Latch operate can be gained by the following equation :

$$C_{PD} \text{ (total)} = 14 + 11 \cdot n$$

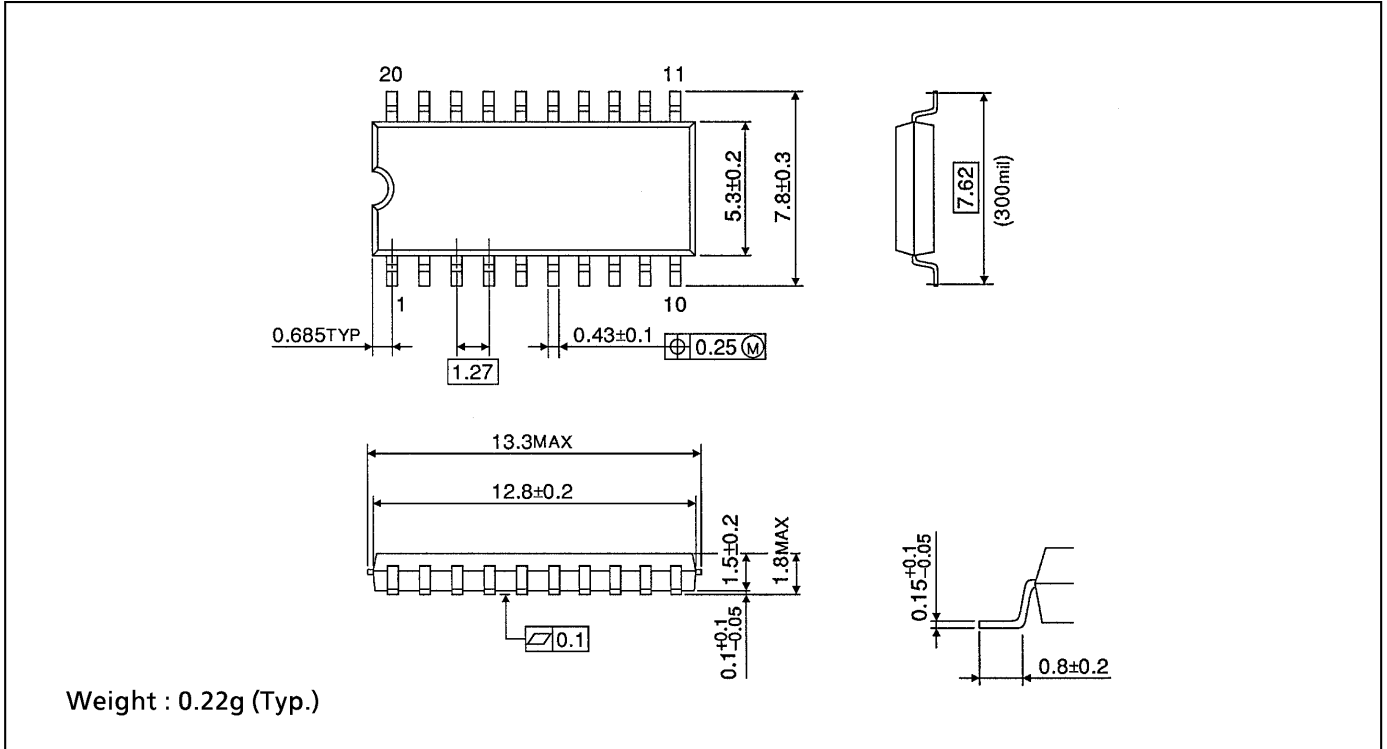
NOISE CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

| PARAMETER | SYMBOL | TEST CONDITION | Ta = 25°C | | | UNIT |
|--|------------------|-----------------------|---------------------|----------------|----------------|------|
| | | | V _{CC} (V) | TYP. | MAX. | |
| Quiet Output Maximum Dynamic V _{OL} | V _{OLP} | C _L = 50pF | 5.0 | 1.1 (1.2) | 1.5 (1.6) | V |
| Quiet Output Minimum Dynamic V _{OL} | V _{OLV} | C _L = 50pF | 5.0 | -1.1 (-1.2) | -1.5 (-1.6) | V |
| Minimum High Level Dynamic Input Voltage | V _{IHD} | C _L = 50pF | 5.0 | — | 2.0 | V |
| Maximum Low Level Dynamic Input Voltage | V _{ILD} | C _L = 50pF | 5.0 | — | 0.8 | V |

(Note) The value in () only applies to JEDEC SOP (FW) devices.

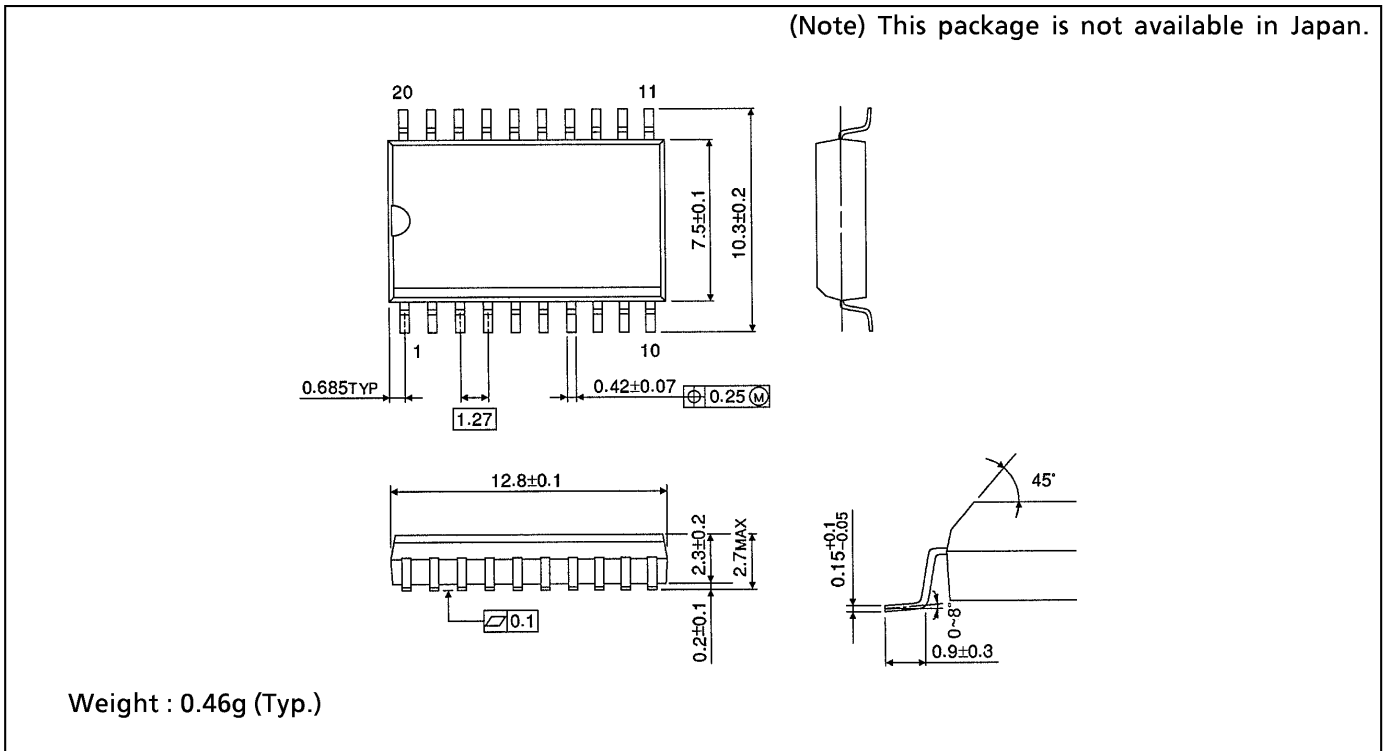
SOP 20PIN (200mil BODY) PACKAGE DIMENSIONS (SOP20-P-300-1.27)

Unit in mm



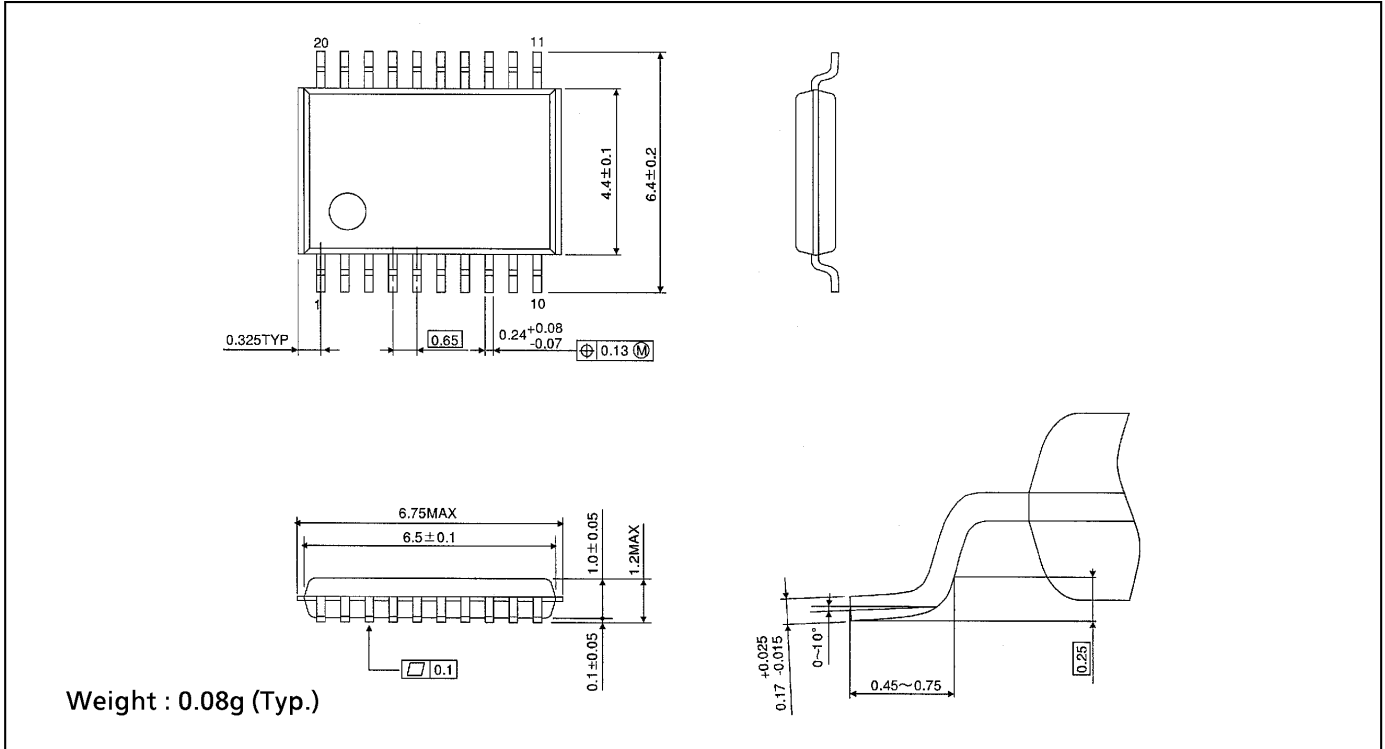
SOP 20PIN (300mil BODY) PACKAGE DIMENSIONS (SOP20-P-300-1.27)

Unit in mm



TSSOP 20PIN PACKAGE DIMENSIONS (TSSOP20-P-0044-0.65)

Unit in mm



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